

	<h2 style="color: #E67E22;">FQB12N50TM_AM002</h2>
 <p>Image may be representation. See specs for product details.</p>	<b>Hersteller-Teilenummer:</b> <a href="#">FQB12N50TM_AM002</a>
	<b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a>
	<b>Teil der Beschreibung:</b> MOSFET N-CH 500V 12.1A D2PAK
	<b>Datenblätter:</b>  <a href="#">FQB12N50TM_AM002.pdf</a>
	<b>RoHs Status:</b> Bleifrei / RoHS-konform
	<b>Lagerzustand:</b> New original, 32363 pcs Stock Available.
	<b>Liefern von:</b> Hong Kong
<b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS	

### Spezifikationen

Teilenummer	<a href="#">FQB12N50TM_AM002</a>
Hersteller	<a href="#">Fairchild/ON Semiconductor</a>
Beschreibung	MOSFET N-CH 500V 12.1A D2PAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	32363 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D <sup>2</sup> PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 179W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	12.1A (Tc)
Rds On (Max) @ Id, Vgs	490 mOhm @ 6.05A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	51nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2020pF @ 25V
Verpackung	Tape & Reel (TR)



















































FQB12N50TM\_AM002 ist neu im Original, Suche FQB12N50TM\_AM002 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB12N50TM\_AM002 Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB12N50TM\_AM002: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <b>FQB12N50</b> FAIRCHILD FQB12N50 FAIRCHILD	 <b>FQB12N60CTM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 12A D2PAK	 <b>FQB12N60</b> FAIRCHI FQB12N60 FAIRCHI	 <b>FQB12N60C</b> Fairchild/ON Semiconductor FQB12N60C FAIRCHILD
 <b>FQB12N50TM_AM002</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 12.1A D2PAK	 <b>FQB12N50TM</b> Original FQB12N50TM Original	 <b>FQB12N50TM_0515+</b> Original	 <b>FQB12N60CTM</b> Fairchild/ON Semiconductor MOSFET N-CH 600V 12A D2PAK

### heiße Teile

Mehr

 FQB10N20C	 FQB10N20CTM	 FQB10N20CTM	 FQB10N20L	 FQB10N20LTM
 FQB10N20LTM	 FQB10N20TM	 FQB10N20TM	 FQB10N50CF	 FQB10N50CFM
 FQB10N50CFM_WS	 FQB10N60C	 FQB10N60CTM	 FQB10N60CTM	 FQB11N40
 FQB11N40C	 FQB11N40CTM	 FQB11N40CTM	 FQB11N60FTM	 FQB11N60TM
 FQB11P06	 FQB11P06TM	 FQB11P06TM	 FQB11P06TM**CN-SCI	 FQB12N50TM
 FQB12N50TM_AM002	 FQB12N60	 FQB12N60C	 FQB12N60CTM	 FQB12N60CTM
 FQB12N60TM	 FQB12N60TM_AM002	 FQB12N60TM_AM002	 FQB12P10	 FQB12P10TM
 FQB12P10TM	 FQB12P20	 FQB12P20TM	 FQB12P20TM	 FQB13N06L
 FQB13N10	 FQB13N10L	 FQB13N50	 FQB13N50CTM	 FQB13N50CTM
 FQB140N03L	 FQB14N30TM	 FQB14N30TM	 FQB16N25TM	 FQB16N25TM

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